

Technical Data Data Sheet N1414, Rev. - STB860 STF860 STD860

Green Products

**ST860** 

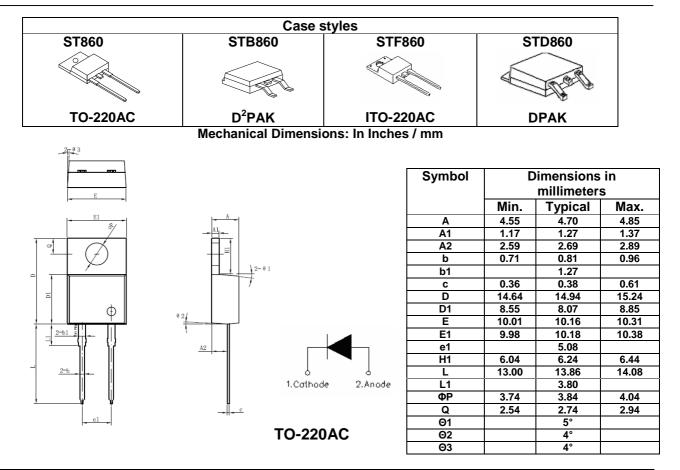
# ST860/STB860/STF860/STD860 SCHOTTKY RECTIFIER

#### **Applications:**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### Features:

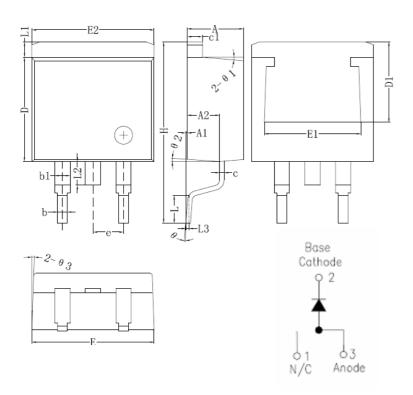
- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



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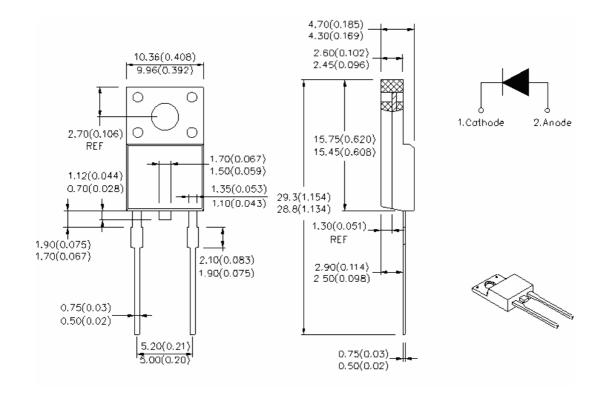
Symbol	Dimensions in			
	millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	<b>8</b> °	
e1		5°		
e2		4°		
e3		<b>4</b> °		

D<sup>2</sup>PAK

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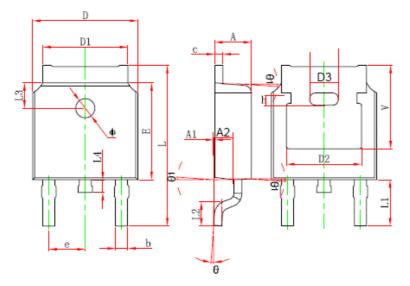


ITO-220AC

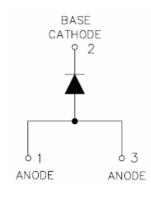
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Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	2.200	2.380	0.087	0.094	
A1	0.000	0.100	0.000	0.004	
b	0.710	0.810	0.028	0.032	
с	0.460	0.560	0.018	0.022	
D	6.500	6.700	0.256	0.264	
D1	5.130	5.460	0.202	0.215	
D2	4.830	REF.	0.190 REF.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	REF.	0.114 REF.		
L2	1.400	1.700	0.055	0.067	
L3	1.600	REF.	0.063 REF.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
A2	0.910	1.110	0.036	0.044	
V	5.350 REF.		0.211 REF.		
D3	1.778REF.		0.070REF.		
h	0.762REF.		0.030REF.		
<del>0</del> 1	7°		7°		



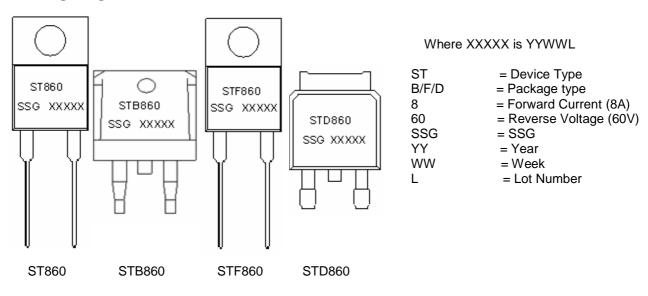
DPAK

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### **Marking Diagram:**



Cautions: Molding resin Epoxy resin UL: 94V-0

### **Ordering Information:**

Device	Package	Shipping	
ST860	TO-220AC(Pb-Free)	50pcs / tube	
STB860	D <sup>2</sup> PAK(Pb-Free)	800pcs / reel	
STF860	ITO-220AC(Pb-Free)	50pcs / tube	
STD860	DPAK(Pb-Free)	2500pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	60	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>c</sub> =100°C, rectangular wave form	8	A
Peak One Cycle Non-Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	130	A

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 8A, Pulse, T <sub>J</sub> = 25 °C	0.70	V
	V <sub>F2</sub>	@ 8A, Pulse, T <sub>J</sub> = 125 °C	0.60	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R$ T <sub>J</sub> = 25 °C	1.12	mA
	I <sub>R2</sub>	$@V_R = rated V_R$ T <sub>J</sub> = 125 °C	40	mA
Junction Capacitance (per leg)	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	450	pF
Voltage Rate of Change	dv/dt	-	10,000	V/µs

\* Pulse Width < 300µs, Duty Cycle <2%

### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	ST860	STB860	STD860	STF860	Units
Junction Temperature	ΤJ	-55 to +150			°C	
Storage Temperature	T <sub>stg</sub>	-55 to +150			°C	
Maximum Thermal Resistance Junction to Case(per leg)*	R <sub>θJC</sub>	3	3	2.4	6	°C/W
Approximate Weight	wt	1.8	1.85	0.39	1.8	g
Case Style	TO-220AC/ D <sup>2</sup> PAK/ DPAK/ ITO-220AC					

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